

FAIRCHILD

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SEMICONDUCTOR

MM74HC4051 • MM74HC4052 • MM74HC4053 8-Channel Analog Multiplexer • Dual 4-Channel Analog Multiplexer • Triple 2-Channel Analog Multiplexer

General Description

The MM74HC4051, MM74HC4052 and MM74HC4053 multiplexers are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Also these switches contain linearization circuitry which lowers the on resistance and increases switch linearity. These devices allow control of up to ±6V (peak) analog signals with digital control signals of 0 to 6V. Three supply pins are provided for V_{CC}, ground, and V_{EE}. This enables the connection of 0-5V logic signals when $V_{CC} = 5V$ and an analog input range of $\pm 5V$ when $V_{FF} = 5V$. All three devices also have an inhibit control which when HIGH will disable all switches to their off state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to $V_{\mbox{\scriptsize CC}}$ and ground.

MM74HC4051: This device connects together the outputs of 8 switches, thus achieving an 8 channel Multiplexer. The binary code placed on the A, B, and C select lines determines which one of the eight switches is "on", and connects one of the eight inputs to the common output. MM74HC4052: This device connects together the outputs of 4 switches in two sets, thus achieving a pair of 4-channel multiplexers. The binary code placed on the A, and B select lines determine which switch in each 4 channel section is "on", connecting one of the four inputs in each section to its commo output. This enables the implementation of a 4-channel differential multiplexer.

MM74HC4053: This device contains 6 switches whose outputs are connected together in pairs, thus implementing a triple 2 channel multiplexer, or the equivalent of 3 singlepole-double throw configurations. Each of the A, B, or C select lines independently controls one pair of switches, selecting one of the two switches to be "on".

Features

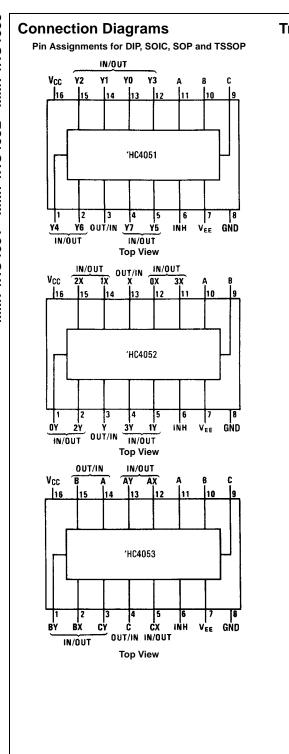
- Wide analog input voltage range: ±6V
- Low "on" resistance:
 - 50 typ. (V_{CC}–V_{EE} = 4.5V)
 - 30 typ. $(V_{CC} V_{EE} = 9V)$
- Logic level translation to enable 5V logic with ±5V analog signals
- Low quiescent current: 80 μA maximum (74HC)
- Matched Switch characteristic

Ordering Code:

Order Number	Package Number	Package Description
MM74HC4051M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4051WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4051SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4051MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4051N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide
MM74HC4052M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4052WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4052SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
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Truth	Tables

MM744051

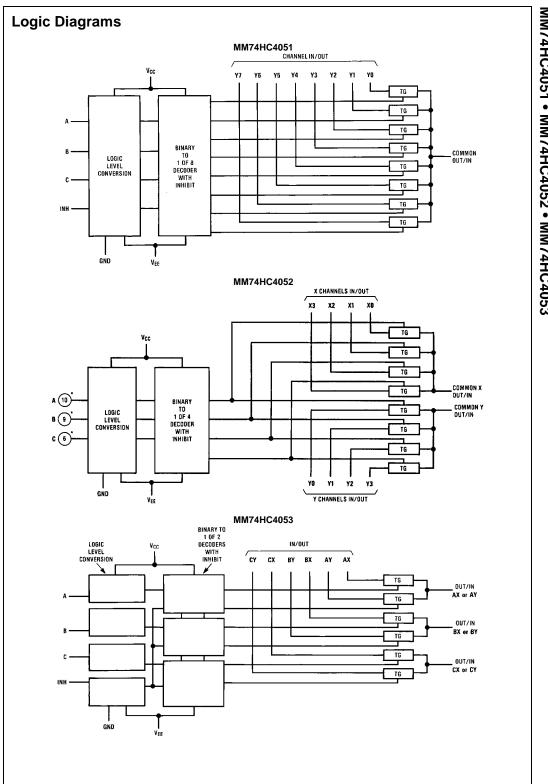
	Inp	ut		"ON"
Inh	С	В	Α	Channel
Н	Х	Х	Х	None
L	L	L	L	Y0
L	L	L	н	Y1
L	L	н	L	Y2
L	L	Н	н	Y3
L	н	L	L	Y4
L	н	L	Н	Y5
L	н	Н	L	Y6
L	н	н	н	Y7

MM744052

In	puts		"ON" C	hannels		
Inh	В	Α	Х	Y		
Н	Х	Х	None	None		
L	L	L	0X	0Y		
L	L	Н	1X	1Y		
L	н	L	2X	2Y		
L	н	н	3X	3Y		

MM744053

	Inp	ut		"ON	" Chan	nels
Inh	С	В	Α	С	b	а
Н	Х	Х	Х	None	None	None
L	L	L	L	СХ	ВX	AX
L	L	L	н	СХ	ВX	AY
L	L	Н	L	СХ	BY	AX
L	L	Н	н	СХ	BY	AY
L	н	L	L	CY	ВX	AX
L	н	L	Н	CY	ВX	AY
L	н	Н	L	CY	BY	AX
L	н	Н	Н	CY	BY	AY



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Absolute Maximum Ratings(Note 1) (Note 2)

Recommended Operating Conditions

Supply Voltage (V _{CC})	-0.5 to +7.5V
Supply Voltage (V _{EE})	+0.5 to -7.5V
Control Input Voltage (VIN)	-1.5 to V _{CC} +1.5V
Switch I/O Voltage (V _{IO})	V_{EE} –0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
Output Current, per pin (I _{OUT})	±25 mA
V_{CC} or GND Current, per pin (I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
Supply Voltage (V _{EE})	0	-6	V
DC Input or Output Voltage			
(V _{IN} , V _{OUT})	0	V_{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those age to the device may occur.	values be	eyond whice	ch dam-

260°C Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter		Conditions	VFF	Vcc	T _A =	$T_A = 25^{\circ}C$ $T_A = -40$ to $85^{\circ}C$ $T_A = -55$ to 1			Units
Symbol	Faramete	ſ	Conditions	*EE	•cc	Тур		Guaranteed Limits		
VIH	Minimum HIGH Leve	I			2.0V		1.5	1.5	1.5	V
	Input Voltage				4.5V		3.15	3.15	3.15	V
					6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Leve	I			2.0V		0.5	0.5	0.5	V
	Input Voltage				4.5V		1.35	1.35	1.35	V
					6.0V		1.8	1.8	1.8	V
R _{ON}	Maximum "ON" Resis	stance	$V_{INH} = V_{IL}, I_S = 2.0 \text{ mA}$	GND	4.5V	40	160	200	240	Ω
	(Note 5)		$V_{IS} = V_{CC}$ to V_{EE}	-4.5V	4.5V	30	120	150	170	Ω
			(Figure 1)	-6.0V	6.0V	20	100	125	140	Ω
			$V_{INH} = V_{IL}, I_S = 2.0 \text{ mA}$	GND	2.0V	100	230	280	320	Ω
			$V_{IS} = V_{CC} \text{ or } V_{EE}$	GND	4.5V	40	110	140	170	Ω
			(Figure 1)	-4.5V	4.5V	20	90	120	140	Ω
			-6.0V	6.0V	15	80	100	115	Ω	
R _{ON}	ON Maximum "ON" Resistance Matching		$V_{CTL} = V_{IL}$	GND	4.5V	10	20	25	25	Ω
			$V_{IS} = V_{CC}$ to GND	-4.5V	4.5V	5	10	15	15	Ω
				-6.0V	6.0V	5	10	12	15	Ω
I _{IN}	Maximum Control		$V_{IN} = V_{CC} or GND$				±0.1	±1.0	±1.0	μA
	Input Current		$V_{CC} = 2 - 6V$							
I _{CC}	Maximum Quiescent		$V_{IN} = V_{CC}$ or GND	GND	6.0V		8	80	160	μA
	Supply Current		$I_{OUT} = 0 \ \mu A$	-6.0V	6.0V		16	160	320	μA
I _{IZ}	Maximum Switch "OF	F"	$V_{OS} = V_{CC} or V_{EE}$	GND	6.0V		±60	±600	±600	nA
	Leakage Current		$V_{IS} = V_{EE} or V_{CC}$	-6.0V	6.0V		±100	±1000	±1000	nA
	(Switch Input)		$V_{INH} = V_{IH}$ (Figure 2)							
I _{IZ}	Maximum Switch		$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.2	±2.0	±2.0	μA
	"ON" Leakage	HC4051	$V_{INH} = V_{IL}$	-6.0V	6.0V		±0.4	±4.0	±4.0	μA
	Current		(Figure 3)							
			$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	μA
		HC4052	$V_{INH} = V_{IL}$ (Figure 3)	-6.0V	6.0V		±0.2	±2.0	±2.0	μA
			$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	μA
		HC4053	V _{INH} = V _{IL} (Figure 3)	-6.0V	6.0V		±0.1	±1.0	±1.0	μA

Symbol	Parameter		Conditions	VEE	v _{cc}	$T_A = 25^{\circ}C$		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
			Conditions	• EE		Тур		Guaranteed L	imits	onita
I _{IZ}	Maximum Switch		$V_{OS} = V_{CC} \text{ or } V_{EE}$	GND	6.0V		±0.2	±2.0	±2.0	μΑ
	"OFF" Leakage	HC4051	$V_{IS} = V_{EE} \text{ or } V_{CC}$	-6.0V	6.0V		±0.4	±4.0	±4.0	μΑ
	Current (Common Pin)		$V_{INH} = V_{IH}$							
			$V_{OS} = V_{CC} \text{ or } V_{EE}$	GND	6.0V		±0.1	±1.0	±1.0	μΑ
		HC4052	$V_{IS} = V_{EE}$ or V_{CC}	-6.0V	6.0V		±0.2	±2.0	±2.0	μΑ
			$V_{INH} = V_{IH}$							
			$V_{OS} = V_{CC} \text{ or } V_{EE}$	GND	6.0V		±0.1	±1.0	±1.0	μΑ
		HC4053	$V_{IS} = V_{EE}$ or V_{CC}	-6.0V	6.0V		±0.1	±1.0	±1.0	μΑ
			$V_{INH} = V_{IH}$							

Note 4: For a power supply of 5V \pm 10% the worst case on resistances (R_{ON}) occurs for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occur for CMOS at the higher voltage and so the 5.5V values should be used.

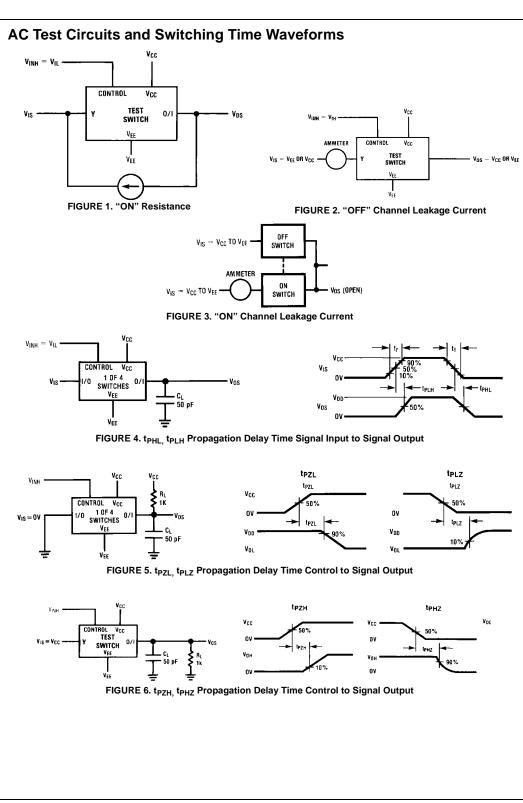
Note 5: At supply voltages (V_{CC}–V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

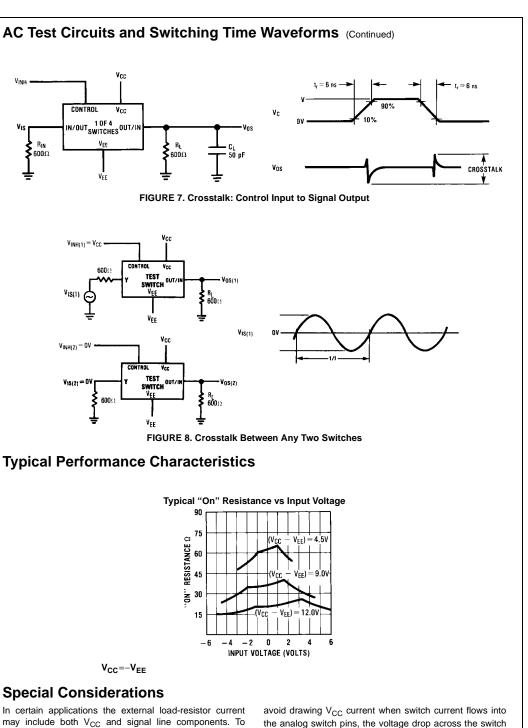
AC Electrical Characteristics

 $V_{CC} = 2.0V-6.0V$, $V_{EE} = 0V-6V$, $C_L = 50$ pF (unless otherwise specified)

Symbol	Parameter	Conditions		VEE	Vcc	$T_A = 25^{\circ}C$		$I_{A} = -40$ to 85°C	$T_A = -55$ to $125^{\circ}C$	Units
Gymbol	rarameter			· EE		Тур	Guaranteed Limits			onna
t _{PHL} , t _{PLH}	Maximum Propagation			GND	2.0V	25	60	75	90	ns
	Delay Switch In to Out			GND	4.5V	5	12	15	18	ns
				-4.5V	4.5V	4	8	12	14	ns
				-6.0V	6.0V	3	7	11	13	ns
t _{PZL} , t _{PZH}	Maximum Switch Turn	$R_L = 1 k\Omega$		GND	2.0V	92	355	435	515	ns
	"ON" Delay			GND	4.5V		69	87	103	ns
				-4.5V	4.5V	16	46	58	69	ns
				-6.0V	6.0V	15	41	51	62	ns
t _{PHZ} , t _{PLZ}	Maximum Switch Turn			GND	2.0V	65	290	365	435	ns
	"OFF" Delay			GND	4.5V	28	58	73	87	ns
				-4.5V	4.5V	18	37	46	56	ns
				-6.0V	6.0V	16	32	41	48	ns
f _{MAX}	Minimum Switch			GND	4.5V	30				MHz
	Frequency Response			-4.5V	4.5V	35				MHz
	20 log (V _I /V _O) = 3 dB									
	Control to Switch	$R_L = 600\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5V	1080				mV
	Feedthrough Noise	f = 1 MHz,	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	250				mV
		$C_L = 50 \text{ pF}$								
	Crosstalk between	$R_L = 600\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5	-52				dB
	any Two Switches		$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	-50				dB
	Switch OFF Signal	$R_L = 600\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5V	-42				dB
	Feedthrough	f = 1 MHz,	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	-44				dB
	Isolation	$V_{CTL} = V_{IL}$								
THD	Sinewave Harmonic	$R_L = 10 \ k\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5V	0.013				%
	Distortion	$C_{L} = 50 \text{ pF},$	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	0.008				%
		f = 1 kHz								
CIN	Maximum Control					5	10	10	10	pF
	Input Capacitance									
CIN	Maximum Switch	Input				15				pF
	Input Capacitance	4051 Commo	on			90				
		4052 Commo	on			45				
		4053 Commo	on			30				
C _{IN}	Maximum Feedthrough Capacitance					5				pF

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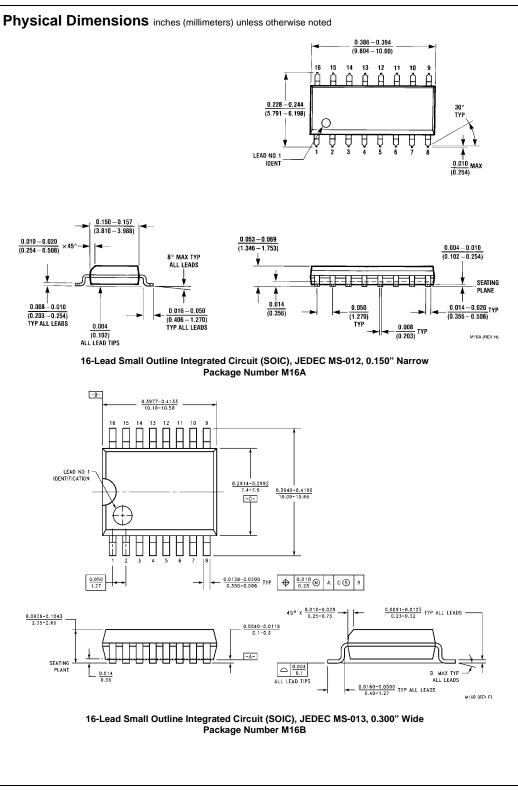


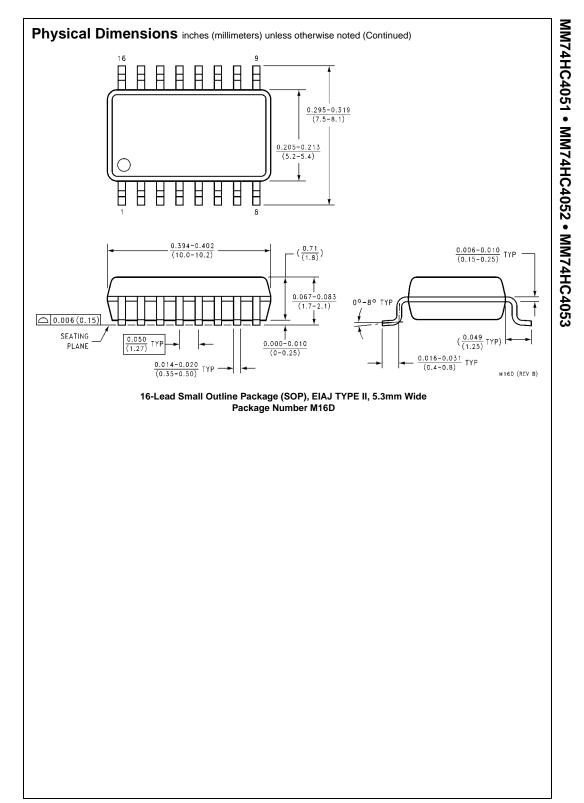


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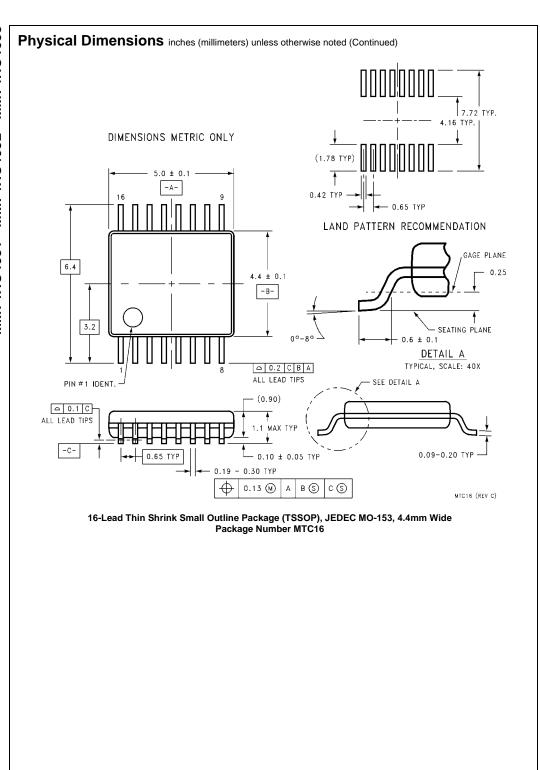
must not exceed 1.2V (calculated from the ON resistance).











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